

View Online at <https://aerobasegroup.com/nsn/5961-01-135-4118>

**Inclosure Material:**

Ceramic

**Overall Length:**

Between 0.750 inches and 0.785 inches

**Overall Height:**

0.200 inches

**Overall Width:**

Between 0.245 inches and 0.271 inches

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-116-2

**Component Name And Quantity:**

16 semiconductor device diode

**Mounting Method:**

Terminal

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

1.5 forward voltage, dc all semiconductor device diode and 60.0 repetitive peak reverse voltage all semiconductor device diode

**Current Rating Per Characteristic:**

350.00 milliamperes source cutoff current preset all transistor

**Power Rating Per Characteristic:**

650.0 milliwatts small-signal input power, common-collector absolute all transistor

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction

**Terminal Type And Quantity:**

14 pin

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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